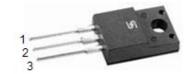




# **Dual Common Cathode Schottky Rectifier**

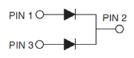
#### **FEATURES**

- Low power loss, high efficiency
- Guardring for overvoltage protection
- High surge current capability
- UL Recognized File # E-326243
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition





#### **ITO-220AB**





#### **MECHANICAL DATA**

Case: ITO-220AB

Molding compound, UL flammability classification rating 94V-0 Base P/N with suffix "G" on packing code - halogen-free Base P/N with prefix "H" on packing code - AEC-Q101 qualified **Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 1A whisker test

with prefix "H" on packing code meet JESD 201 class 2 whisker test

Polarity: As marked

**Mounting torque:** 5 in-lbs maximum **Weight:** 1.7 g (approximately)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°ℂ unless otherwise noted)										
		MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	
PARAMETER	SYMBOL	1035	1045	1050	1060	1090	10100	10150	10200	UNIT
		СТ	СТ	СТ	СТ	СТ	СТ	СТ	СТ	
Maximum repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	90	100	150	200	V
Maximum RMS voltage	$V_{RMS}$	24	31	35	42	63	70	105	140	V
Maximum DC blocking voltage	$V_{DC}$	35	45	50	60	90	100	150	200	V
Maximum average forward rectified current	I <sub>F(AV)</sub>				10					Α
Peak repetitive forward current (Rated VR, Square wave, 20KHz)	I <sub>FRM</sub>	10				Α				
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	120				Α				
Peak repetitive reverse surge current (Note 1)	I <sub>RRM</sub>	0.5					Α			
Maximum instantaneous forward voltage (Note 2) I <sub>F</sub> = 5 A, T <sub>J</sub> =25℃		0.	70	0.	80	0.	85	0.	88	
I <sub>F</sub> = 5 A, T <sub>J</sub> =125℃	$V_{F}$	0.	57	0.	65	0.	75	0.	78	V
I <sub>F</sub> = 10 A, T <sub>J</sub> =25℃		0.	80	0.	90	0.	95	0.9	98	
I <sub>F</sub> = 10 A, T <sub>J</sub> =125℃		0.	67	0.	75	0.	85	0.8	88	
Maximum reverse current @ rated VR T <sub>J</sub> =25 °C		0.1								
T <sub>J</sub> =125 ℃	I <sub>R</sub>	1	15	1	0			5		mA
Voltage rate of change (Rated V <sub>R</sub> )	dV/dt	10000			V/µs					
Typical thermal resistance	$R_{ heta JC}$	3.5			°C/W					
Operating junction temperature range	TJ	- 55 to +150			οС					
Storage temperature range	T <sub>STG</sub>	- 55 to +150			οС					
Note 1: tn = 2.0 us 1.0KHz	•	-								-

Note 1:  $tp = 2.0 \mu s$ , 1.0KHz

Note 2: Pulse test with PW=300µs, 1% duty cycle

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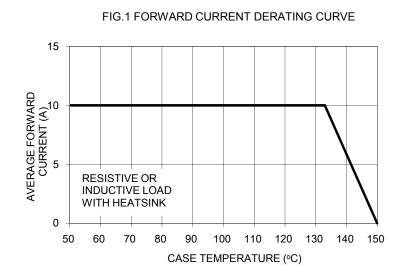
ORDERING INFORMATION						
PART NO.	AEC-Q101	PACKING CODE	GREEN COMPOUND	PACKAGE	PACKING	
	QUALIFIED		CODE			
MBRF10xxCT (Note 1)	Prefix "H"	C0	Suffix "G"	ITO-220AB	50 / Tube	

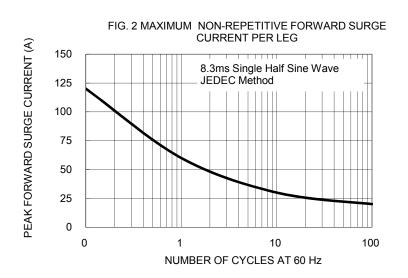
Note 1: "xx" defines voltage from 35V (MBRF1035CT) to 200V (MBRF10200CT)

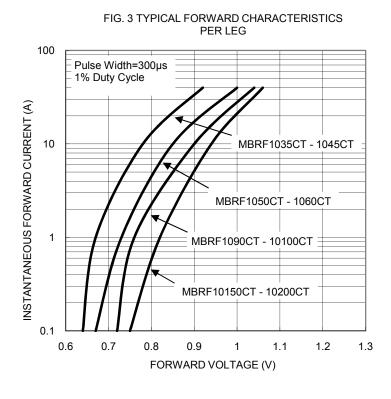
EXAMPLE							
PREFERRED P/N	PART NO.	AEC-Q101	PACKING CODE	GREEN COMPOUND	DESCRIPTION		
	TAKT NO.	QUALIFIED	. 7.01	CODE			
MBRF1060CT C0	MBRF1060CT		C0				
MBRF1060CT C0G	MBRF1060CT		C0	G	Green compound		
MBRF1060CTHC0	MBRF1060CT	Н	C0		AEC-Q101 qualified		

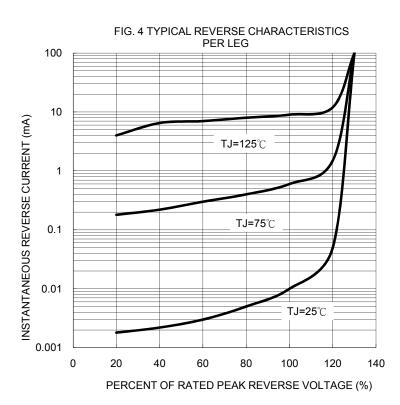
#### **RATINGS AND CHARACTERISTICS CURVES**

(TA=25°C unless otherwise noted)



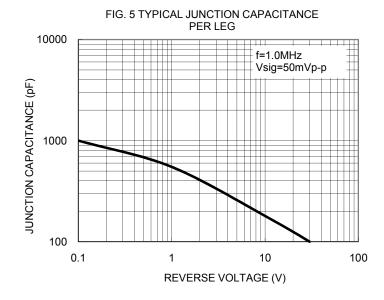


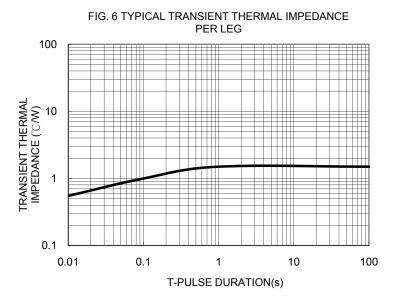




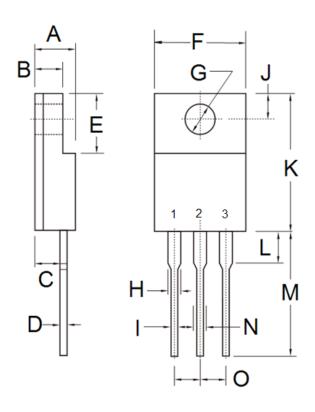








#### **PACKAGE OUTLINE DIMENSIONS**



DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	4.30	4.70	0.169	0.185	
В	2.50	3.16	0.098	0.124	
С	2.30	2.96	0.091	0.117	
D	0.46	0.76	0.018	0.030	
E	6.30	6.90	0.248	0.272	
F	9.60	10.30	0.378	0.406	
G	3.00	3.40	0.118	0.134	
Η	0.95	1.45	0.037	0.057	
I	0.50	0.90	0.020	0.035	
J	2.40	3.20	0.094	0.126	
K	14.80	15.50	0.583	0.610	
L	-	4.10	1	0.161	
М	12.60	13.80	0.496	0.543	
N	-	1.80	-	0.071	
0	2.41	2.67	0.095	0.105	

### **MARKING DIAGRAM**



P/N = Specific Device Code G = Green Compound

G = Green Compound YWW = Date Code

F = Factory Code

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